## NSN 5962-01-352-7923

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Body Length:	
0.640 inches	
Body Width:	
Between 0.300 inches and 0.420 inches	
Body Height:	
Between 0.045 inches and 0.090 inches	
Maximum Power Dissipation Rating:	
1.04 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Electrostatic sensitive and hermetically sealed and burn in and monolithic	;
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Flat pack	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
14 input	
Case Outline Source And Designator:	
F-6 mil-m-38510	
Current Rating Per Characteristic:	
190.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
-0.3 volts power source and 7.0 volts power source	
Capitance Rating Per Characteristic:	
15.00 input picofarads and 12.00 output picofarads	
Time Rating Per Chacteristic:	
40.00 nanoseconds access	
Memory Device Type:	
Prom	
Special Features:	
Nuclear hardness critical items	
Nuclear Hardness Critical Feature:	
Hardened	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards	in

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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## Terminal Type And Quantity:

24 flat leads

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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